Enhanced Ferromagnetism and Tunable Magnetism in Fe$_3$GeTe$_2$ Monolayer by Strain Engineering

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ABSTRACT: Recent discovery of intrinsic ferromagnetism in Fe$_3$GeTe$_2$ (FGT) monolayer [Deng, Y.; et al. Nature 2018, 563, 94–99; Fei, Z.; et al. Nat. Mater. 2018, 17, 778–782] not only extended the family of two-dimensional (2D) magnetic materials but also stimulated further interest in the possibility to tune their magnetic properties without changing the chemical composition or introducing defects. By means of density functional theory computations, we explore strain effects on the magnetic properties of the FGT monolayer. We demonstrate that the ferromagnetism can be largely enhanced by the tensile strain in the FGT monolayer due to the competitive effects of direct exchange and superexchange interaction. The average magnetic moments of Fe atoms increase monotonically with an increase in biaxial strain from −5 to 5% in FGT monolayer. The intriguing variation of magnetic moments with strain in the FGT monolayer is related to the charge transfer induced by the changes in the bond lengths. Given the successful fabrication of the FGT monolayer, the strain-tunable ferromagnetism in the FGT monolayer can stimulate the experimental effort in this field. This work also suggests an effective route to control the magnetic properties of the FGT monolayer. The pronounced magnetic response toward the biaxial strain can be used to design the magnetomechanical coupling spintronics devices based on FGT.

KEYWORDS: Fe$_3$GeTe$_2$ monolayer, two-dimensional materials, ferromagnetism, magnetic properties, strain engineering

INTRODUCTION

Two-dimensional (2D) materials, such as graphene, boron nitride, ternary boron–carbon–nitrogen systems, and transition-metal dichalcogenides, have demonstrated their great potentials in nanoelectronics due to their fascinating properties. However, these materials are nonmagnetic, which limits their use in spintronic devices. Encouragingly, first-principles calculations indicated that magnetism can be induced in these systems by defects and/or impurities. Thus, significant efforts have been made to introduce magnetism through defect engineering, e.g., by cutting graphene into ribbons, introducing transition-metal atoms, and creating vacancy defects in these 2D materials. Unfortunately, although localized magnetic moments can be created using these methods, it is difficult to introduce long-range ferromagnetic ordering in these nonmagnetic 2D materials.

The very recently experimentally realized 2D materials with intrinsic ferromagnetic ordering can help overcome all these limitations, providing them with great potentials for new spintronics applications. It has been experimentally demonstrated that monolayer CrI$_3$ is an Ising ferromagnet with an out-of-plane spin orientation and a Curie temperature of 45 K. A recent study has shown that ferromagnetic order is present in the ultrathin layered material Cr$_x$Ge$_y$Te$_z$ at low temperatures. The magnetism in bilayer CrI$_3$ and few-layered Cr$_x$Ge$_y$Te$_z$ can be further controlled by electric field. In addition to CrI$_3$ and Cr$_x$Ge$_y$Te$_z$, other novel 2D ferromagnets have been proposed. Among these 2D ferromagnetic materials, Fe$_3$GeTe$_2$ (FGT) is particularly promising, as ferromagnetism persists in FGT down to the monolayer, and the Curie temperature of the FGT monolayer is 130 K, which is higher than that of other 2D ferromagnetic materials found experimentally. Although 2D ferromagnetic order has been found experimentally in the FGT monolayer, the use of this system in actual applications requires the ability to tune its magnetic properties and enhance the stability of the ferromagnetism. Thus, achieving precise control over magnetic moments and ferromagnetic stability through external parameters is highly desirable for the practical applications of this material in spintronics.

Strain engineering, sometimes referred to as “straintronics”, is a promising route to modulate the electronic
and magnetic properties of 2D materials. It has been demonstrated that graphene can be tuned from metallic to insulating by applying strain along different crystallographic directions. The optical band gap of MoS₂ membranes can be continuously tuned by an applied biaxial strain. It was predicted that the tensile strain along the zigzag direction can greatly enhance the ferromagnetic stability of graphene with a topological line defect, while the tensile strain along the armchair direction quickly reduces magnetic moments. The half-fluorinated BN and GaN layers exhibit an interesting magnetic transition from antiferromagnetism to ferromagnetism by applying strain, and a half-metallic behavior can be achieved at the 6% compression. Likewise, ferromagnetism was predicted in layered NbSe₂ and NbSSe₂ under a biaxial tensile strain. The induced magnetic moments can also be obviously enhanced by the tensile strain. In the V₂ monolayers (X = S, Se), the magnetic coupling and magnetic moments were predicted to increase rapidly with increasing strain, which arises from strong ionic–covalent bonds. These results strongly indicate that a systematic study of the strain effect on the magnetic behavior of the FGT monolayer is highly desirable.

In this work, by means of density functional theory (DFT) calculations, we explore the strain effect on the magnetic properties of the FGT monolayer. We show that the tensile strain can considerably enhance the ferromagnetism of the FGT monolayer. The strain-tunable ferromagnetism in the FGT monolayer predicted in our simulations can stimulate the experimental effort in this field. In addition, the average magnetic moments of Fe atoms increase monotonically with increasing strain from −5 to 5% in the FGT monolayer. The result suggests that strain engineering is an effective route to achieve large tunability of magnetic properties in the FGT monolayer.

■ COMPUTATIONAL METHOD

Our DFT calculations were performed using the VASP package within the projector-augmented wave (PAW) method. Spin-polarized local density approximation (LDA) was used as the exchange-correlation functional. The previous studies have demonstrated that LDA + U, PBE, and PBE + U functionals overestimate the magnetic moments for bulk FGT and FGT monolayer, whereas LDA can accurately describe the FGT system. Hence, the LDA functional was chosen in our work. The energy cutoff of the plane wave basis set was 600 eV. The structures were relaxed until the energy and the force on each atom were less than 10⁻⁵ eV and 0.005 eV/Å, respectively. The k-point sampling of 29 × 29 × 1 was used for the unit cell of the FGT monolayer, and a 10 × 20 × 1 k-point mesh was used for the 2 × 1 × 1 supercell. A vacuum spacing of 16 Å was introduced to avoid the interlayer interactions between the periodic images of the system.

■ RESULTS AND DISCUSSION

The FGT monolayer has been successfully fabricated by Xu's and Zhang’s groups. The FGT monolayer is composed of five atomic layers: the top and bottom sublayers are Te atoms, the second and fourth sublayers are Fe1 and Fe2 atoms, and the middle sublayer is made up of Fe3 and Ge atoms (Figure 1a). There are two inequivalent Fe sites in the FGT monolayer, where Fe1 and Fe2 atoms are located at the equivalent sites, while Fe3 atom has the inequivalent site. Our DFT calculation showed that the lattice parameter of the FGT monolayer is 3.91 Å, which is in a good agreement with the previous results. The bond lengths and the bond angles are presented in Table S1 of the Supporting Information. Spin-density distribution in the FGT monolayer (Figure S1, Supporting Information) indicates that the magnetic moments dominantly localize on Fe atoms, and the average local magnetic moment of Fe atoms is 1.53 μB, which agrees with the previous studies. The spin-polarized band structure of the FGT monolayer (Figure 1b) exhibits a metallic behavior for the spin-up and spin-down channels, similar to its bulk. The partial density of states (PDOS) analysis (Figure S2, Supporting Information) indicates that the Fe d orbitals mainly contribute to the metallicity.

The FGT monolayer is known to have a ferromagnetic (FM) coupling of magnetic moments localized on Fe atoms, and the FM-ordered spin is more desirable in practical applications in spintronic devices. However, it is not clear how the strain influences the FM spin ordering of the FGT monolayer. Therefore, we studied strain effect on the stability of ferromagnetism in the FGT monolayer. The strain effects were modeled by applying the in-plane biaxial strain along the lattice vectors. The biaxial strain is defined as ε = Δc/c₀, where c₀ and c = c₀ ± Δc are the unstrained and strained lattice constants of the FGT monolayer, respectively. To examine the stability of the FGT monolayer under the tensile and compressive strains, we perform the phonon spectrum calculation of the FGT monolayer at −5, −3, 0, 3, and 5% strains, respectively. It can be seen from Figure S3a–d that the FGT monolayer is dynamically stable at −3, 0, 3, and 5% strains. However, it is evident from Figure S3e that the FGT monolayer is unstable at −5% compressive strain. It can thus be concluded that the FGT monolayer is dynamically stable under the tensile strain and moderate compressive strain but unstable at large compressive strain. We note, experimentally, strain engineering of 2D materials is done by transferring the 2D material on a flexible substrate making use of lattice constant or thermal-expansion mismatch. The substrate can then increase the stability of the FGT monolayer. Therefore, following the previous theoretical studies, we explore the stability of ferromagnetism in the FGT monolayer with a strain from −5% (compressive) to 5% (tensile).
To investigate the magnetic couplings between the magnetic moments localized on Fe atoms, we examine the spin configurations for the FGT monolayer using a $2 \times 1 \times 1$ supercell. According to the spin ordering of Fe atoms, four typical magnetic structures were considered, which are depicted in Figure 2a: (i) the FM state, with FM spin ordering at each Fe atoms, denoted by FM; (ii) the antiferromagnetic (AFM) state, with FM spin ordering at Fe1 and Fe2 atoms, the AFM spin ordering with Fe3 atom in the same cell, but with opposite ordering in the different cell, denoted by AFM1; (iii) the AFM state, with FM-ordered spins at Fe1, Fe2, and Fe3 atoms in the same cell, but with opposite ordering in the different cell, denoted by AFM2; (iv) the AFM state, with FM spin ordering at Fe1 and Fe3 atoms, AFM spin ordering with Fe2 atom in the same cell, but with opposite ordering in the different cell, denoted by AFM3. Figure 2b displays the spin density distribution of the four magnetic structures. Note that the AFM2 configuration in the FGT monolayer is not stable, and it will transfer to the AFM1 coupling after geometry optimization (see Figure 2b). The FM coupling is the lowest energy state, which is more stable than the AFM1 and AFM3 configurations by an energy difference of 106 and 97 meV, respectively. We also construct other representative AFM configurations, such as AFM4, AFM5, AFM6, and AFM7 (Figure S4, Supporting Information). It is found that these AFM configurations in the FGT monolayer are not stable.

The energy difference $\Delta E = E_{\text{AFM3}} - E_{\text{FM}}$ at various strain values is presented in Figure 2c. Here, $E_{\text{AFM3}}$ and $E_{\text{FM}}$ are the total energies of the AFM3 and FM configurations, respectively. It is found that the energy difference exhibits a significant increase with increasing strain from $-5$ to 5% for the FGT monolayer. As the tensile strain increases, the energy difference rapidly increases and reaches 451 meV at 5% strain, nearly 5 times higher than that in the unstrained FGT. At the same time, the FM stability of the FGT monolayer is remarkably enhanced, as evidenced by the increased energy difference with tensile strain. However, for the compressive strain on FGT, the energy difference decreases with higher compression, and the FM coupling is weakened. This indicates that the tensile strain can significantly enhance the FM stability of the FGT monolayer.

To understand if the FM coupling could be experimentally implemented, we considered a possible structural breakage in the considered range of strain. Figure 2d exhibits the variation of strain energy with applied strain: the strain energy is a quadratic function of strain. This indicates that the FM coupling holds in the elastic range, which has potential applications in electromechanical nanodevices.

The stability of FM coupling can be understood using the Goodenough–Kanamori–Anderson (GKA) rules. The magnetic ground state of the FGT monolayer is governed by the direct exchange interaction and the superexchange interaction. For the direct exchange interaction, the $d$ orbitals on the nearest-neighbor Fe atoms overlap directly, without a mediation atom. Thus, it gives rise to AFM coupling, which is governed by the distance between the neighboring Fe atoms. On the other hand, for the superexchange interaction, the $d$ orbitals on the nearest-neighbor Fe atoms overlap with the $p$ orbitals of Ge or Te atoms. Consequently, the superexchange mediated by Ge or Te atoms gives rise to FM coupling. The FM coupling strength is mainly sensitive to the Fe–Te (Ge)–Fe angle. If superexchange interaction is stronger than direct exchange interaction, FGT exhibits FM coupling, otherwise it shows AFM coupling.

The three different paths for superexchange interaction between the nearest-neighbor Fe atoms in the FGT monolayer are shown in Figure 3a. Figure 3b,c shows the dependence of the Fe–Te (Ge)–Fe angle on FGT, the energy difference decreases with higher compression, and the FM coupling is weakened. This indicates that the tensile strain can significantly enhance the FM stability of the FGT monolayer.

![Image](https://example.com/image.png)
the distance and the Fe–Te (Ge)–Fe angle on strain. As the strain increases, the distances of Fe1–Fe1 (d1) and Fe1–Fe3 (d2) increase, while that of Fe1–Fe2 (d3) decreases. The angles of Fe1–Te–Fe1 (θ1) and Fe1–Te–Fe3 (θ2) increase, whereas that of Fe1–Ge–Fe2 (θ3) decreases as the strain increases. The delicate balance and the competing nature of the direct exchange and superexchange interactions under the applied strain result in the stability of FM coupling. In addition, as Fe atoms have a nearly filled d-shell, there is a relatively small spatial hybridization between Fe atoms but a strong Fe–Te (Ge) covalent interaction, which leads to the direct exchange interaction being smaller than the superexchange interaction and thus a weakened AFM direct exchange, and the FM coupling becomes more stable than the AFM coupling.

To gain further insight into the magnetic properties of the FGT monolayer with applied strain, we examined the spin-density distributions (Figure 4a). Evidently, external strain has significant effect on the magnetic properties of the FGT monolayer. We further examined the strain dependence of the magnetic moments of atoms (Figure 4b,c). For simplification, the magnetic moments of Fe1 and Fe3 atoms in the FGT monolayer are named as MFe1 and MFe3 and that of Ge and Te atoms are named as MGe and MTe, respectively. We found that MFe1 increases monotonically with increase in strain from −5 to 5% in the FGT monolayer. Under tensile strain, MFe1 reaches 2.26 μB at ε = 5%, approximately 126% increment compared to the case of undeformed FGT monolayer. For the compressive strain, MFe1 decreases down to 1.46 μB at ε = −5%. Different from the case of MFe1, MFe3 first decreases and then increases slightly with increase in strain from −5 to 5%. MFe3 is calculated to be 1.33 μB, 1.02 μB, and 1.11 μB at ε = −5, 0, and 5%, respectively. Despite distinct changes in MFe1 and MFe3, the average magnetic moment of Fe atoms increases monotonically with increasing strain from −5 to 5% in the FGT monolayer. On the other hand, MGe (MTe) also increases with strain from 0.039 μB (0.019 μB) at −5% to 0.071 μB (0.028 μB) at 5%. The results suggest that Fe atoms mainly contribute spin polarizations, while Ge and Te atoms contribute little to the magnetism. The spin polarizations in the FGT monolayer are robust for a wide range of strain. As mentioned above, the structural breakage will not occur in a large elastic range. Therefore, the large elastic range will provide the possibility to modulate the spin state and the magnetic properties by applying tensile or compressive strains.

The interesting changes in the magnetic moments with strain can be understood by examining the bond lengths, the charge transfer, and the PDOS of the FGT monolayer under −5, 0, and 5% strain. The geometric details of the FGT monolayer under a biaxial strain are presented in Figure 5a. Due to the Poisson effect, the stretching of the in-plane biaxial direction will result in contraction in the perpendicular direction. Thus, upon applying biaxial strain on the FGT monolayer, the distance of Fe1–Fe2 and the bond length of Fe3–Te (denoted as dFe1–Fe2 and dFe3–Te) are reduced in the perpendicular direction, whereas the bond lengths of Fe1–Te and Fe3–Ge (denoted as dFe1–Te and dFe3–Ge) increase in the plane direction. We note that the bond lengths dFe1–Te and dFe3–Ge increase by 5.75 and 10.53% for the FGT monolayer at a 5% tensile strain as compared to that at a −5% compressive strain.

Figure 4. (a) Spin-density distribution of the FGT monolayer with −5, 0, and 5% strain. The isovalue is 0.02 e/Å³. Panel (b) shows strain dependence of magnetic moment (µB) per Fe1 and Fe3 atoms and (c) per Ge and Te atoms in the FGT monolayer.

Figure 5. Strain dependence of (a) the distance and the bonding length (Fe1–Fe2 distance, dFe1–Fe2; Fe3–Te bond length, dFe3–Te; Fe3–Ge bond length, dFe3–Ge; Fe1–Te bond length, dFe1–Te), (b) Electron transfer of Fe, Ge, and Te atoms in the FGT monolayer. PDOS of (c) Fe1 atom and (d) Fe3 atom in the FGT monolayer under −5, 0, and 5% biaxial strain, respectively.
strain. Due to the change of the bond length, the obvious charge transfer in the FGT monolayer was observed (Figure Sb). Each Fe1 (Te) atom loses (gains) about 0.08 (0.08), 0.14 (0.11), and 0.21 (0.19) electron charge at $-5\%$, 0, and $5\%$ strain, respectively. On the other hand, each Fe3 (Ge) atom gains (loses) about 0.25 (0.19), 0.13 (0.06), and 0.16 (0.07) electron charge at $-5\%$, 0, and $5\%$ strain, respectively. The charge transfer between Fe1 and Te (Fe3 and Ge) atoms has a completely opposite trend, implying that the charge transfer mainly happens between Fe1 and Te (Fe3 and Ge) atoms. Furthermore, we found that the amount of charge transferred from the Fe1 atom increases monotonically, whereas that of the Fe3 atom first decreases then increases slightly with increase in strain from $-5\%$ to $5\%$, which has a similar trend with the change in magnetic moment of Fe1 (Fe3) atoms with strain (Figure 4b). Due to the charge transfer, it can be also seen from Figure 5c that the spin splitting of the Fe1 3d orbital near the Fermi level becomes larger with increasing strain from $-5\%$ to $5\%$, as is evident from the enhanced spin splitting of the a and b states in PDOS (Figure 5c), which gives rise to an increase in the magnetic moments of Fe1 atoms with strain. At the same time, for Fe3 atoms, the spin polarization is increased at $-5\%$ compressive strain and $5\%$ tensile strain as compared to the unstrained FGT monolayer (Figure 5d), which results in the increase in the magnetic moments of Fe3 atoms with increasing compressive and tensile strains, respectively. Therefore, the charge transfer between Fe1 and Te (Fe3 and Ge) atoms can be viewed as an important mechanism for the variation in the magnetic moment of the FGT monolayer with strain.

### CONCLUSIONS

In summary, spin-polarized DFT calculations have been performed to investigate the magnetic properties of the FGT monolayer under biaxial strain. We show that the stability of ferromagnetism can be largely enhanced by the tensile strain in the FGT monolayer due to the competitive effects of direct exchange and superexchange interactions. The magnetic moments of the Fe1 atoms increase monotonically with increasing strain in the FGT monolayer, whereas the magnetic moments of the Fe3 atoms first decrease then increase slightly with change in strain from $-5\%$ to $5\%$. A detailed analysis revealed that the observed variation in the magnetic moment of the FGT monolayer arises from the charge transfer induced by the changes in the bond lengths under strain. Given the successful fabrication and observation of intrinsic ferromagnetism in the FGT monolayer, we strongly believe that this study will stimulate the experimental effort in this field, and strain engineering can serve as an effective way to control the magnetic properties of the FGT monolayer, which can greatly facilitate the development of spintronic devices based on 2D materials. The pronounced magnetic response toward biaxial strain in the FGT monolayer can also greatly facilitate the development of the magnetomechanical coupling spintronic devices.

### ASSOCIATED CONTENT

**Supporting Information**

The Supporting Information is available free of charge at [https://pubs.acs.org/doi/10.1021/acsami.0c05530](https://pubs.acs.org/doi/10.1021/acsami.0c05530).

Spin-density distribution, bond length, bond angle, and PDOS of the FGT monolayer; phonon spectrum of the FGT monolayer at different strains; and other representative AFM configurations (PDF).

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#### Notes

The authors declare no competing financial interest.

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